

N-channel 100 V, 40 mOhm, standard level Trench MOSFET in MLPAK33

21 September 2023

Product data sheet

### 1. General description

General purpose MOSFET for standard applications, 17 A, standard level N-channel enhancement mode Power MOSFET in MLPAK33 package.

### 2. Features and benefits

- Standard level compatibility
- Trench MOSFET technology
- Thermally efficient package in a small form factor (3.3 mm x 3.3 mm footprint)

### 3. Applications

- Secondary side synchronous rectification
- DC-to-DC converters
- Home appliance
- Motor drive
- Load switching
- LED lighting

### 4. Quick reference data

### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 150 °C		-	-	100	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>		-	-	17	А
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>		-	-	21	W
Tj	junction temperature			-55	-	150	°C
Static chara	acteristics	·		·			
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>		-	36	40	mΩ
Dynamic ch	naracteristics						
Q <sub>GD</sub>	gate-drain charge	I <sub>D</sub> = 5 A; V <sub>DS</sub> = 50 V; V <sub>GS</sub> = 10 V;		-	1.5	-	nC
Q <sub>G(tot)</sub>	total gate charge	T <sub>j</sub> = 25 °C; <u>Fig. 11;</u> <u>Fig. 12</u>		-	6.6	-	nC
Avalanche	ruggedness			-			
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$\label{eq:ID} \begin{array}{l} I_D = 9.5 \text{ A}; \ V_{sup} \leq \ 100 \text{ V}; \ V_{GS} = 10 \text{ V}; \\ T_{j(init)} = 25 \ ^\circ\text{C}; \ unclamped \end{array}$	[1]	-	-	9	mJ

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Source-drain d	iode						
Qr		$I_{S} = 5 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V}; \\ \text{V}_{DS} = 50 \text{ V}; \text{ T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 15}$	[2]	-	19	-	nC

[1] Protected by 100% test

[2] includes capacitive recovery

# 5. Pinning information

### Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	1 2 3 4	
2	S	source	حف-ف-ف-ف-	
3	S	source		D
4	G	gate		
5	D	drain		G-UF-4
6	D	drain	Цеееи	mbb076 S
7	D	drain		
8	D	drain	MLPAK33 (SOT8002-1)	

# 6. Ordering information

# Table 3. Ordering information Type number Package Name Description Version PXN040-100QS MLPAK33 plastic thermal enhanced surface mounted package; mini leads; 8 terminals; pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body SOT8002-1

# 7. Marking

Table 4. Marking codes	
Type number	Marking code
PXN040-100QS	7AS

# 8. Limiting values

### Table 5. Limiting values

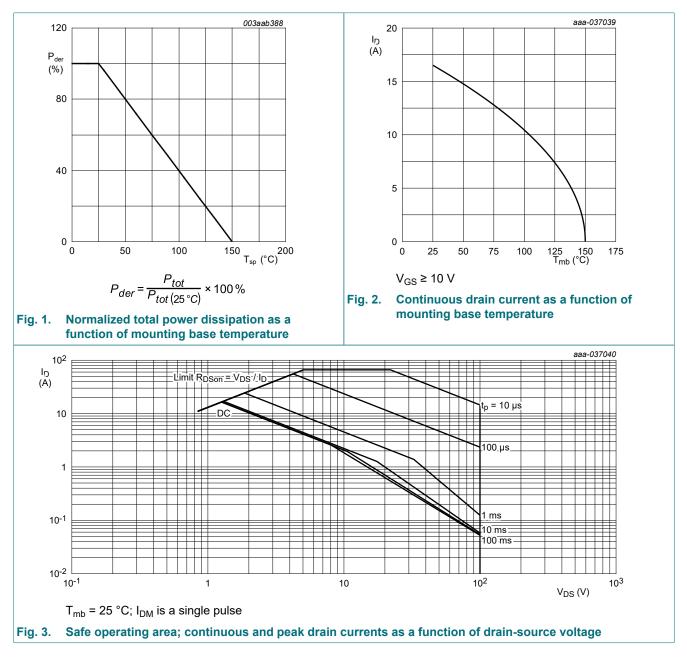
In accordance with the Absolute Maximum Rating System (IEC 60134). Tj = 25 °C unless otherwise stated.

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 150 °C	-	100	V
V <sub>GS</sub>	gate-source voltage		-20	20	V
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>	-	21	W
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	-	17	А
		V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C; <u>Fig. 2</u>	-	10	А
I <sub>DM</sub>	peak drain current	pulsed; $t_p \le 10 \ \mu s$ ; $T_{mb} = 25 \ ^{\circ}C$ ; Fig. 3	-	66	А
T <sub>stg</sub>	storage temperature		-55	150	°C

### N-channel 100 V, 40 mOhm, standard level Trench MOSFET in MLPAK33

Symbol	Parameter	Conditions		Min	Max	Unit
Tj	junction temperature			-55	150	°C
T <sub>sld(M)</sub>	peak soldering temperature			-	260	°C
Source-drai	n diode		-			
ls	source current	T <sub>mb</sub> = 25 °C		-	17	А
I <sub>SM</sub>	peak source current	pulsed; $t_p \le 10 \ \mu s$ ; $T_{mb} = 25 \ ^{\circ}C$		-	66	А
Avalanche r	uggedness					
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$\begin{split} I_D &= 9.5 \text{ A};  \text{V}_{\text{sup}} \leq \ 100  \text{V};  \text{V}_{\text{GS}} = 10  \text{V}; \\ \text{T}_{j(\text{init})} &= 25 ^{\circ}\text{C}; \text{ unclamped} \end{split}$	[1]	-	9	mJ
I <sub>AS</sub>	non-repetitive avalanche current	T <sub>j(init)</sub> = 25 °C	[1]	-	9.5	A

[1] Protected by 100% test



# 9. Thermal characteristics

# Table 6. Thermal characteristicsSymbolParameterConditionsMinTypMaxUnitR<sub>th(j-mb)</sub>thermal resistance from<br/>junction to mounting<br/>baseFig. 4-56K/W



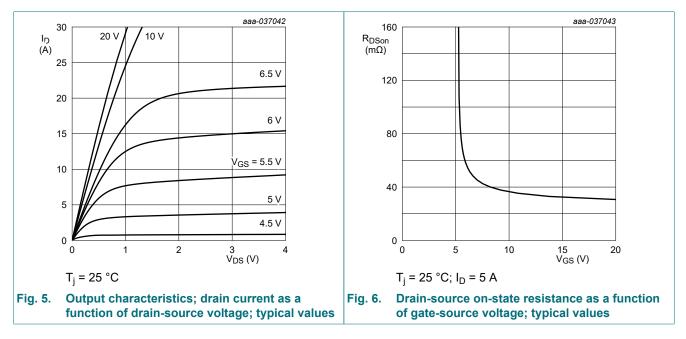
# **10. Characteristics**

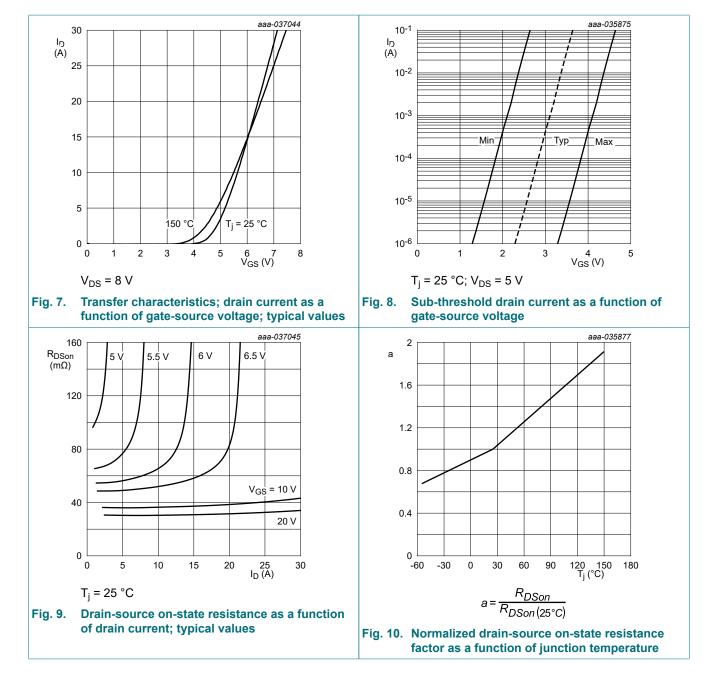
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	teristics					
V <sub>(BR)DSS</sub>	drain-source	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	100	-	-	V
	breakdown voltage	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = -55 °C	-	100	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	$I_D = 0.25 \text{ mA}; V_{DS}=V_{GS}; T_j = 25 \text{ °C};$ Fig. 8	2	3	4	V
		I <sub>D</sub> = 0.25 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = 150 °C	-	1.9	-	V
		I <sub>D</sub> = 0.25 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = -55 °C	-	3.5	-	V
$\Delta V_{GS(th)} / \Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T <sub>j</sub> ≤ 150 °C	-	-8.7	-	mV/K
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 100 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	0.01	1	μA
		V <sub>DS</sub> = 100 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 150 °C	-	-	3	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	2	100	nA
		V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	2	100	nA
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	36	40	mΩ
	resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 150 °C; Fig. 10	-	-	76	mΩ
R <sub>G</sub>	gate resistance	f = 1 MHz; T <sub>i</sub> = 25 °C	-	0.6	-	Ω

PXN040-100QS

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Dynamic ch	aracteristics		1				
Q <sub>G(tot)</sub>	total gate charge	$I_{D} = 5 \text{ A}; V_{DS} = 50 \text{ V}; V_{GS} = 10 \text{ V}; T_{j} = 25 \text{ °C}; Fig. 11; Fig. 12$		-	6.6	-	nC
		$I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V};$ $T_j = 25 \text{ °C}$		-	5.5	-	nC
Q <sub>GS</sub>	gate-source charge	I <sub>D</sub> = 5 A; V <sub>DS</sub> = 50 V; V <sub>GS</sub> = 10 V;		-	2.3	-	nC
Q <sub>GS(th)</sub>	pre-threshold gate- source charge	<sup>–</sup> T <sub>j</sub> = 25 °C; <u>Fig. 11</u> ; <u>Fig. 12</u>		-	1.3	-	nC
Q <sub>GS(th-pl)</sub>	post-threshold gate- source charge			-	1	-	nC
Q <sub>GD</sub>	gate-drain charge			-	1.5	-	nC
V <sub>GS(pl)</sub>	gate-source plateau voltage	I <sub>D</sub> = 5 A; V <sub>DS</sub> = 50 V; T <sub>j</sub> = 25 °C; <u>Fig. 11;</u> Fig. 12		-	5.2	-	V
C <sub>iss</sub>	input capacitance	$V_{DS} = 50 \text{ V}; V_{GS} = 0 \text{ V}; \text{ f} = 1 \text{ MHz};$ $T_j = 25 \text{ °C}; Fig. 13$		-	351	-	pF
C <sub>oss</sub>	output capacitance			-	114	-	pF
C <sub>rss</sub>	reverse transfer capacitance			-	6	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 50 V; R <sub>L</sub> = 10 Ω; V <sub>GS</sub> = 10 V;		-	3.3	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$		-	2.1	-	ns
t <sub>d(off)</sub>	turn-off delay time			-	5.6	-	ns
t <sub>f</sub>	fall time	_		-	4.4	-	ns
Q <sub>oss</sub>	output charge	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 50 V; f = 1 MHz; T <sub>j</sub> = 25 °C		-	8.8	-	nC
Source-drai	in diode						
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 5 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C; <u>Fig. 14</u>		-	0.86	1.2	V
t <sub>rr</sub>	reverse recovery time	$I_{S} = 5 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$		-	28	-	ns
Q <sub>r</sub>	recovered charge	$V_{DS} = 50 \text{ V}; \text{ T}_{\text{j}} = 25 \text{ °C}; \text{ Fig. 15}$	[1]	-	19	-	nC

[1] includes capacitive recovery

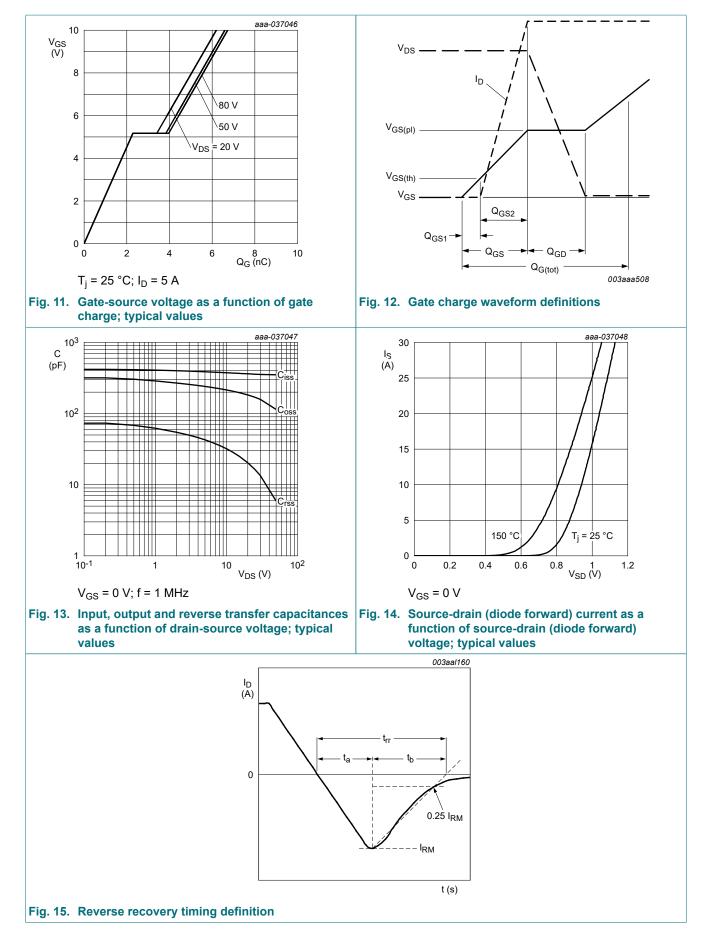




**Product data sheet** 

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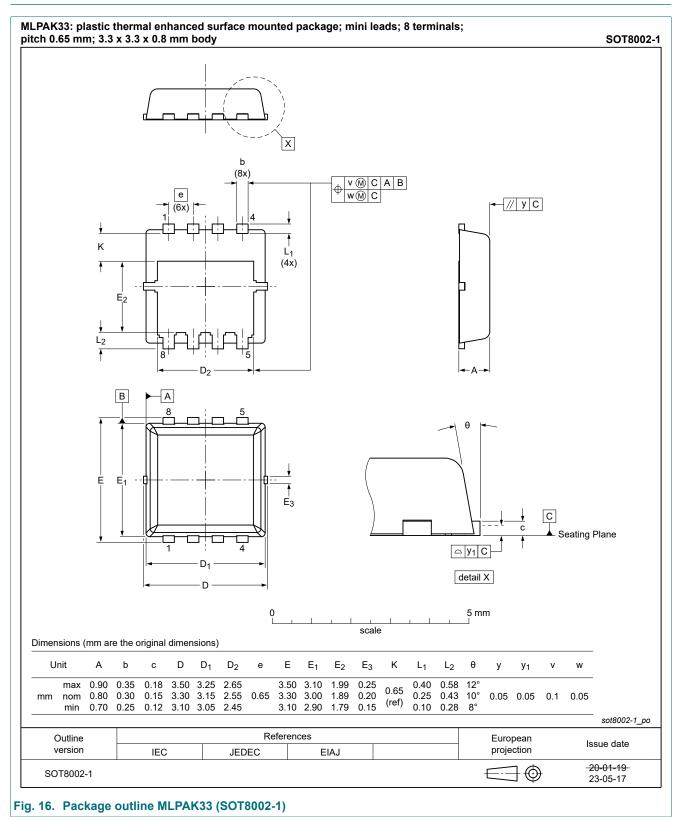


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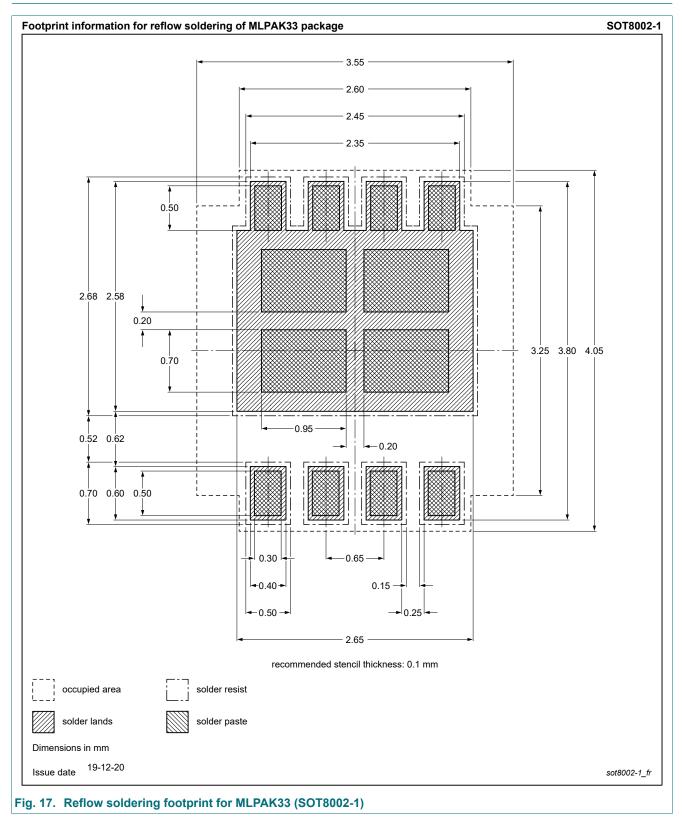
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# **11. Package outline**



# 12. Soldering



# 13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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# Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	2
9.	Thermal characteristics	4
10.	. Characteristics	4
11.	Package outline	8
12.	. Soldering	9
	. Legal information	

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